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MMST4126

25V PNP SMALL SIGNAL TRANSISTOR IN SOT323

Features

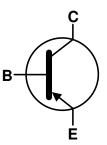
- BV_{CEO} > -25V
- I_C = -200mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: MMST4124
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

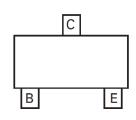
- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)







Device Symbol



Pin-Out Top View

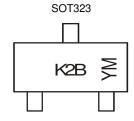
Ordering Information (Note 4)

Ī	Product	Status	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	MMST4126-7-F	Active	AEC-Q101	K2B	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



K2B = Product Type Marking Code YM = Date Code Marking Y or \underline{Y} = Year (ex: D = 2016) M or \underline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	0	2011	2012	2013	2014	2015	201	6 20	17 2	2018	2019	2020
Code	Х		Υ	Z	Α	В	С	D	[F	G	Н
Month	ı	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code)	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-4	V
Collector Current	I _C	-200	mA

Thermal Characteristics (@TA = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_d	200	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	T _i , T _{STG}	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Thermal Characteristics and Derating Information

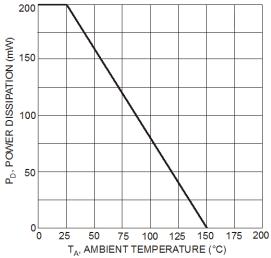


Fig. 1 Max Power Dissipation vs. Ambient Temperature

^{5.} For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



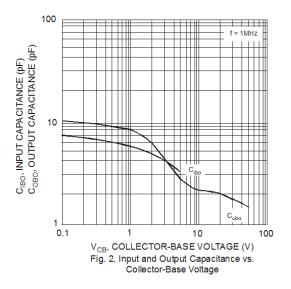
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

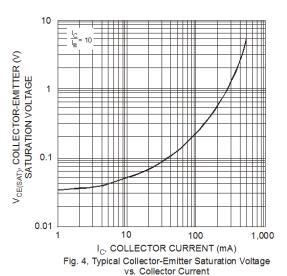
Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						
Collector-Base Breakdown Voltage	BV _{CBO}	-25		V	$I_C = -10\mu A, I_E = 0$	
Collector-Emitter Breakdown Voltage	BV _{CEO}	-25	_	V	$I_C = -1 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	BV _{EBO}	5	_	V	$I_E = -10\mu A, I_C = 0$	
Collector Base Cut-Off Current	I _{CBO}		-50	nA	$V_{CB} = -20V, I_{E} = 0$	
Collector Cut-Off Current	I _{EBO}	_	-50	nA	$V_{EB} = 5V, I_{E} = 0$	
ON CHARACTERISTICS (Note 7)						
DC Current Gain	h _{FE}	120 60	360		$I_C = -2.0 \text{mA}, V_{CE} = -1.0 \text{V}$	
Do Guilent Gain			_		$I_C = -50 \text{mA}, V_{CE} = -1.0 \text{V}$	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		-0.40	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		-0.95	V	$I_C = -50 \text{mA}, I_B = -5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C_{obo}		4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$	
Input Capacitance	Cibo		10	рF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_{C} = 0$	
Small Signal Current Gain	h _{fe}	120	480	_	$V_{CE} = 1.0V$, $I_{C} = -2.0mA$, $f = 1.0kHz$	
Current Gain-Bandwidth Product	f⊤	250	_	MHz	V _{CE} = -20V, I _C = -10mA, f = 100MHz	
Noise Figure	NF	_	4.0	dB	$V_{CE} = -5.0V$, $I_{C} = -100\mu A$, $R_{S} = 1.0k\Omega$, $f = 1.0kHz$	

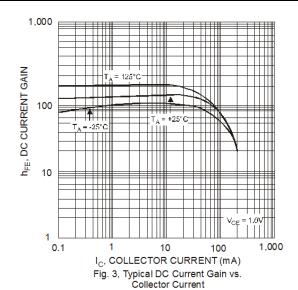
Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

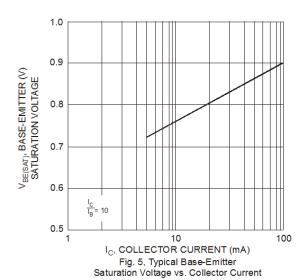


Typical Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)





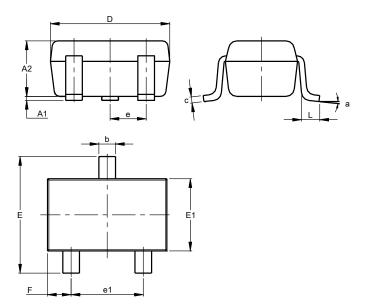






Package Outline Dimensions

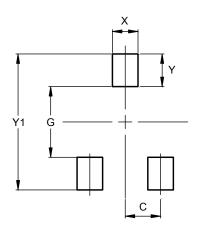
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
E 2.00		2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.470
Υ	0.600
Y1	2.500



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